## NSN 5961-01-615-9362

No Fiig: A110a0

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View Online at https://aerobasegroup.com/nsn/5961-01-615-9362 **Inclosure Material:** Plastic **Overall Length:** 9.652 inches **Overall Height:** 4.445 inches **Overall Width:** 9.525 inches **Function For Which Designed:** Bidirectional Voltage Rating In Volts Per Characteristic: 5.0 gate trigger voltage, instantaneous **Current Rating Per Characteristic:** 0.8 amperes total power dissipation **Capacitance Rating In Picofarads:** 3.0 **Special Features:** Small 8pin package, low drive powerrequired (ttl /cmos compatible), highreliability, arc free with no snubbing circuit, fcc compatible, vde compatble, no emi generation, machine insertable, wave solderable, meets approvals with: ul recognized component: file e76270, en/iec 60950-1 certified component: tuvcertificate b 09 07 49410 004 Shelf Life: N/a **Unit Of Measure: Demilitarization:**